



Product Description

GRF2070 is a broadband, linear, ultra-low noise amplifier designed for small cell, wireless infrastructure and other high performance RF applications requiring ultra-low NF, high gain and linearity.

Configured as a first stage LNA, linear driver or cascaded gain block, it offers high levels of reuse both within a design and across platforms.

GRF2070 is a member of a family of pin compatible, ultra low noise devices which cover a wide range of frequency bands with industry leading NF and gain:

GRF2070: 0.4 to 1.5 GHz

GRF2071: 0.7 to 2.7 GHz

GRF2072: 2.3 to 3.8 GHz

GRF2073: 3.0 to 6.0 GHz

Consult with the GRF applications engineering team for application notes, custom tuning/evaluation board data and device s-parameters.

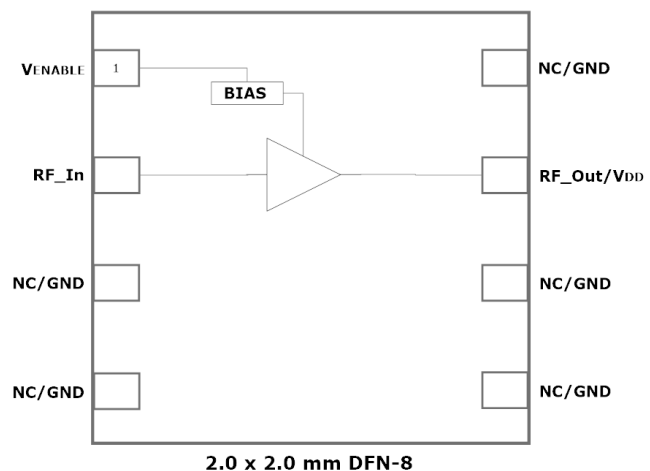
Features

Reference: 5V/75mA/0.9 GHz

- Gain: 21.2 dB
- Eval Board NF: 0.38 dB
- OP1dB: 20.4 dBm
- OIP3: 38.8 dBm
- Flexible Bias Voltage and Current
- Process: GaAs pHEMT

Applications

- Cellular Infrastructure
- Small Cells and Cellular Repeaters
- Distributed Antenna Systems





Preliminary

GRF2070

Ultra-Low Noise Amplifier
Tuning Range: 0.4 – 1.5 GHz

Absolute Ratings:

Parameter	Symbol	Min.	Max.	Unit
Supply Voltage	V _{DD}	0	6.0	V
RF Input Power: (Load VSWR < 2:1; V _D : 5.0 volts)	P _{IN MAX}		23	dBm
Operating Temperature (Package Heat Sink)	T _{AMB}	-40	105	°C
Maximum Channel Temperature (MTTF > 10 ⁶ Hours)	T _{MAX}		170	°C
Maximum Dissipated Power	P _{DISS MAX}		500	mW
Electrostatic Discharge:				
Charged Device Model:	CDM	1500		V
Human Body Model:	HBM	500		V
Storage:				
Storage Temperature	T _{STG}	-65	150	°C
Moisture Sensitivity Level	MSL		1	--



Caution! ESD Sensitive Device

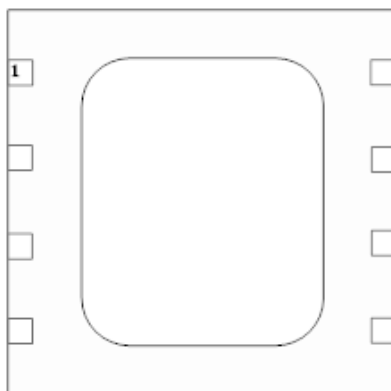


Exceeding Absolute Maximum Rating conditions may cause permanent damage to the device.

Note: For package dimensions and manufacturing information, see the Guerrilla-RF.com website for the following document located on the GRF2070 landing page: **Manufacturing Note—MN-001 Product Tape and Reel, Solderability and Package Outline Specification.**

[Link to manufacturing note](#)

Pin Out (Top View)



Pin Assignments:

Pin	Name	Description	Note
1	VENABLE	Enable Voltage Input	VENABLE and series resistor set I _{DDQ} . VENABLE < =0.2 volts disables device. On -die pull-down resistor will turn the part off if this node is allowed to float.
2	RF_In	RF Input	External match must provide DC block
3	NC/GND	No Connect or Ground	No internal connection to die
4	NC/GND	No Connect or Ground	No internal connection to die
5	NC/GND	No Connect or Ground	No internal connection to die
6	NC/GND	No Connect or Ground	No internal connection to die
7	RF_Out/VDD	RF Output	Provide device V _{DD} via external bias inductor
8	NC/GND	No Connect or Ground	No internal connection to die
PKG BASE	GND	Ground	Provides DC and RF ground for LNA, as well as thermal heat sink. Recommend multiple 8 mil vias beneath the package for optimal RF and thermal performance. Refer to evaluation board top layer graphic on schematic page.



Preliminary

GRF2070

Ultra-Low Noise Amplifier
Tuning Range: 0.4 – 1.5 GHz

Nominal Operating Parameters:

Parameter	Symbol	Specification			Unit	Condition
		Min.	Typ.	Max.		
Gain Mode (Venable high)						$V_{DD} = 5.0\text{ V}$, $T_A = 25\text{ }^\circ\text{C}$
Test Frequency	F_{TEST}		900		MHz	700 to 960 MHz Tune
Evaluation Board Gain	S21		21.2		dB	
Evaluation Board Noise Figure	NF		0.38		dB	Evaluation Board SMA to SMA
Output 3rd Order Intercept Point	OIP3		38.8		dBm	+4.0 dBm P_{OUT} per tone at 2 MHz Spacing (899 and 901 MHz)
Output 1dB Compression Point	OP1dB		20.4		dBm	
Switching Rise Time	T_{RISE}		1800		ns	
Switching Fall Time	T_{FALL}		900		ns	
Supply Current	I_{DD}		70		mA	Adjustable for optimal IP3
Enable Current	I_{ENABLE}		3.5		mA	
Thermal Data						
Thermal Resistance (measured via IR scan)	Θ_{jc}		54		$^\circ\text{C}/\text{W}$	On standard evaluation board
Channel Temperature @ +85 C Reference (Package Heat Sink)	$T_{CHANNEL}$		104		$^\circ\text{C}$	$V_{DD}: 5.0\text{ V}$; $I_{DDQ}: 70\text{ mA}$; No RF; $P_{DISS}: 350\text{ mW}$

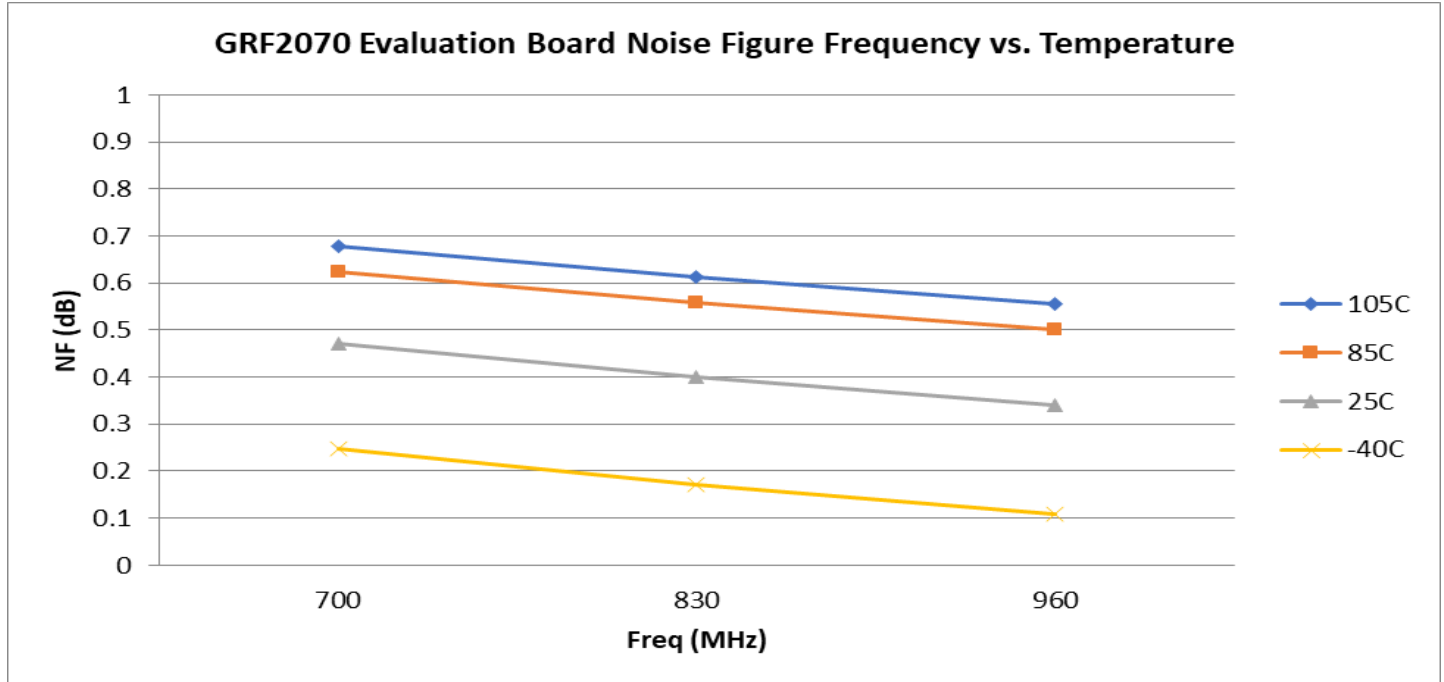
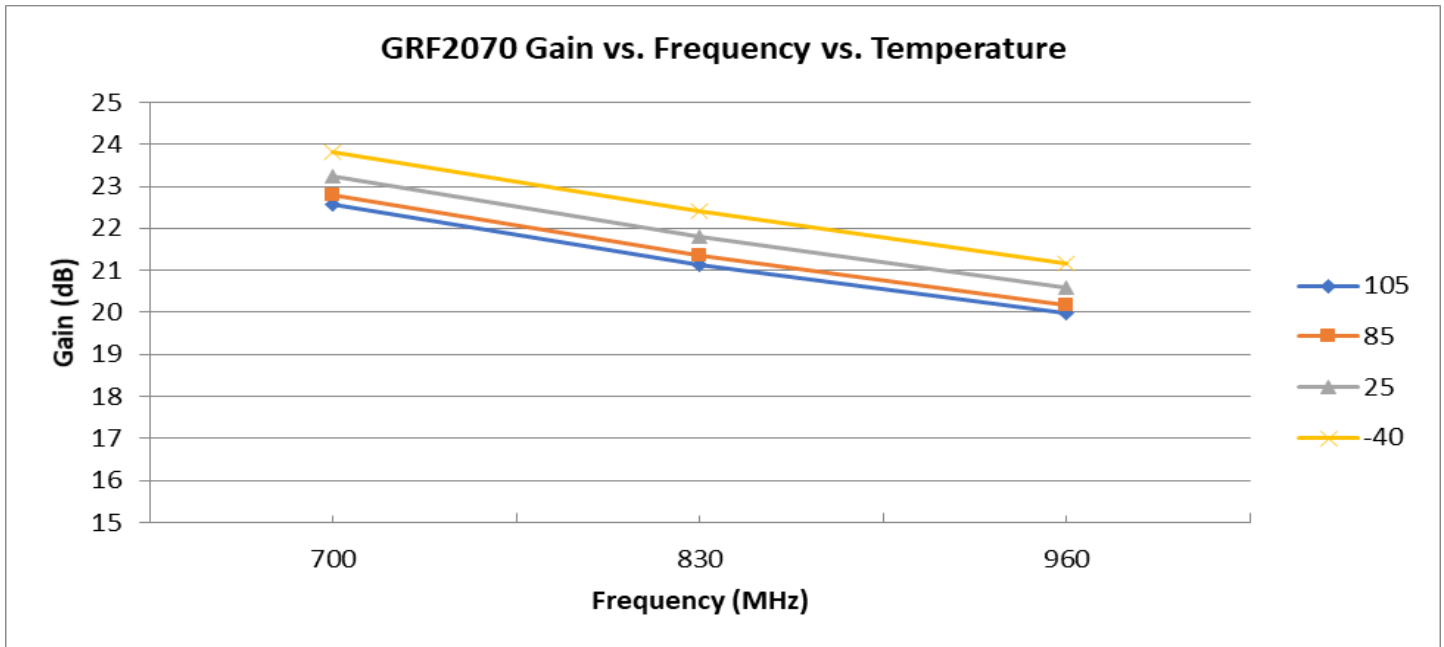


Preliminary

GRF2070

Ultra-Low Noise Amplifier
Tuning Range: 0.4 - 1.5 GHz

GRF2070 Evaluation Board Measured Data:



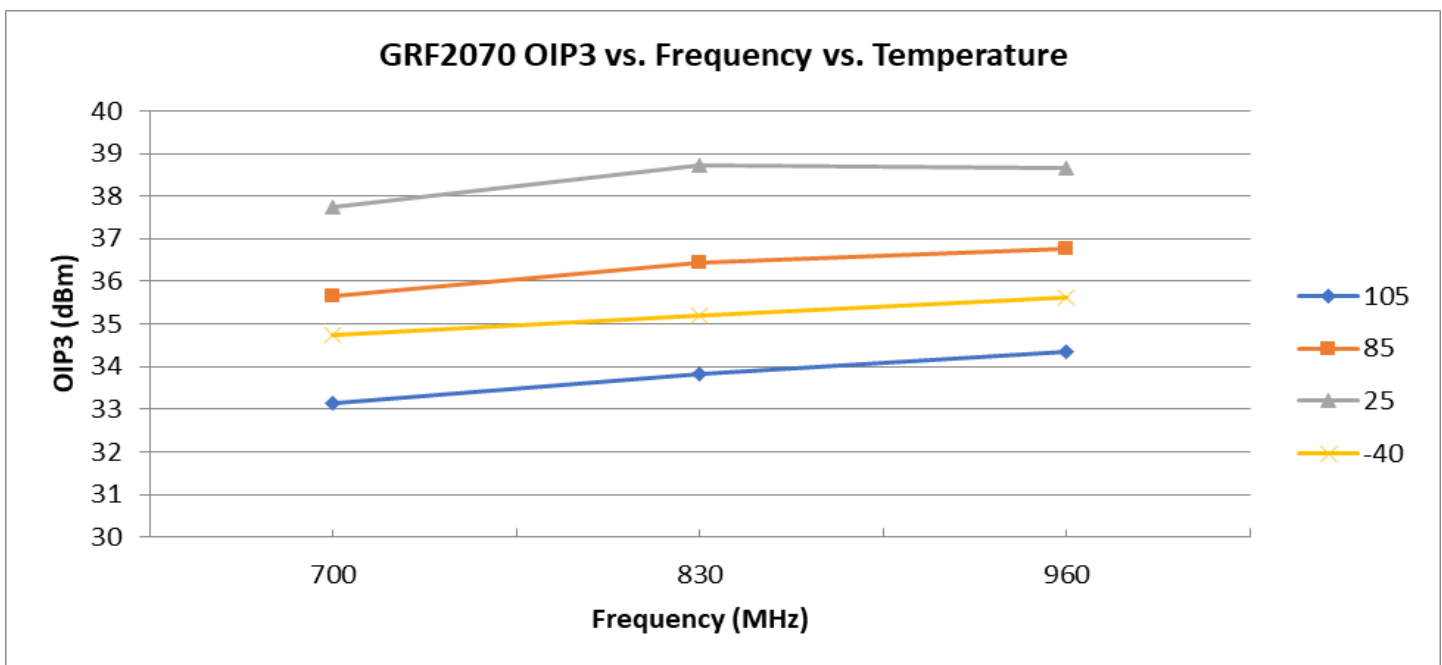
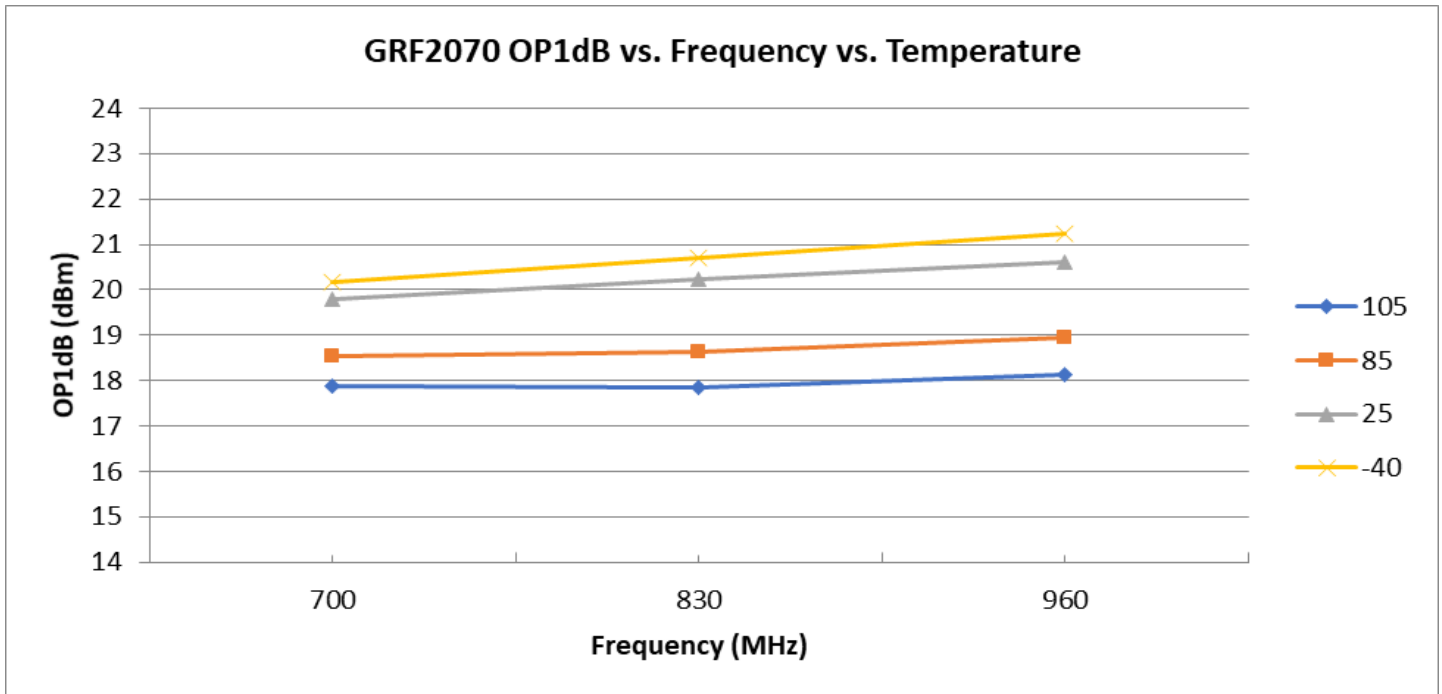


Preliminary

GRF2070

Ultra-Low Noise Amplifier
Tuning Range: 0.4 – 1.5 GHz

GRF2070 Evaluation Board Measured Data:



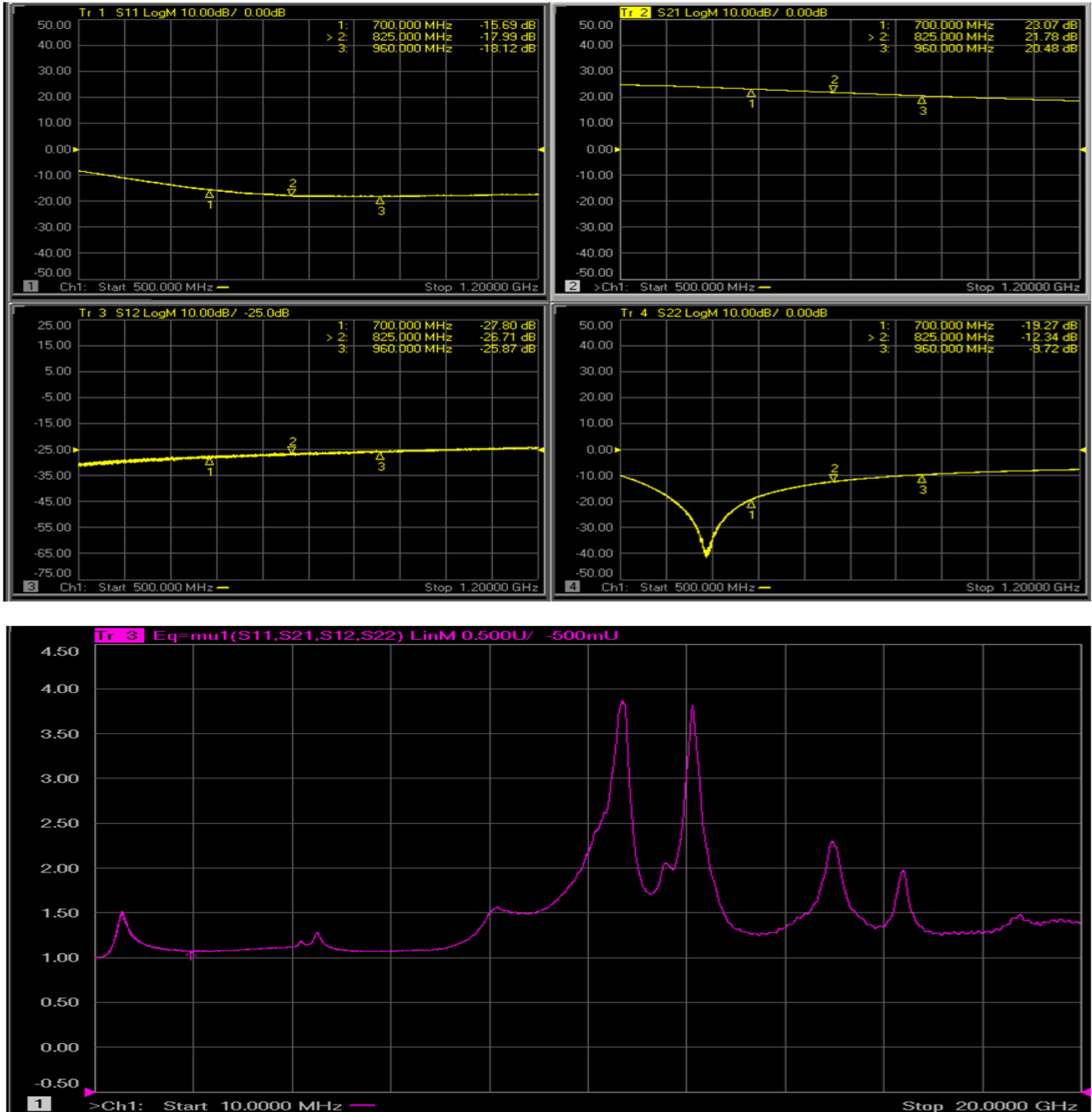


Preliminary

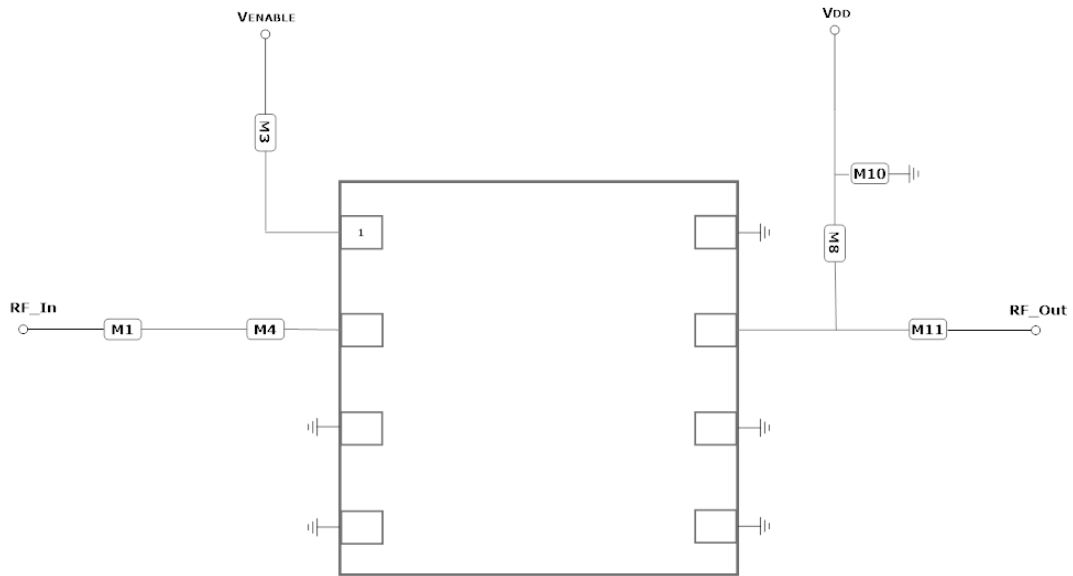
GRF2070

Ultra-Low Noise Amplifier
Tuning Range: 0.4 – 1.5 GHz

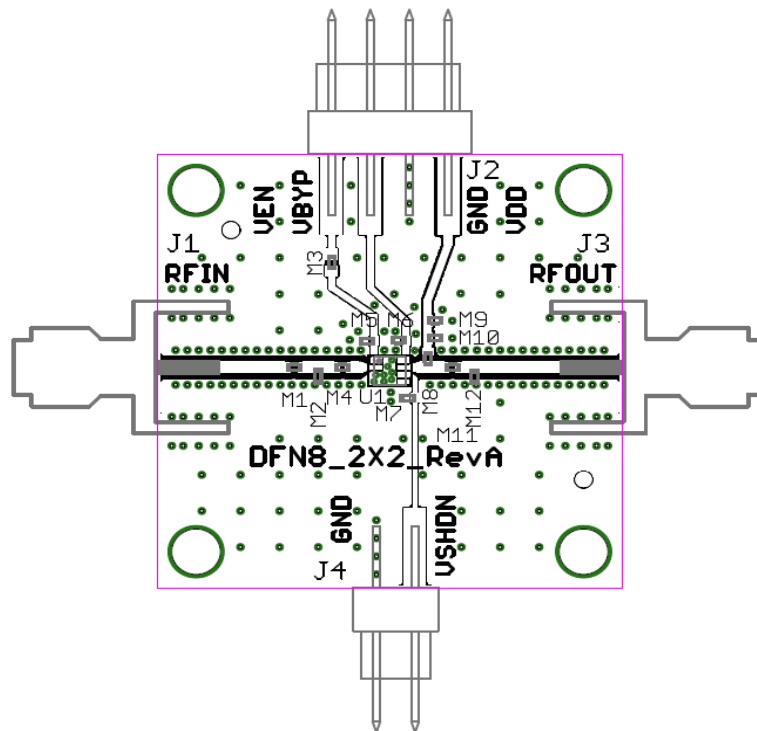
GRF2070 Evaluation Board S-Parms: (0.7 to 0.96 GHz Match)



Note: Mu factor ≥ 1.0 implies unconditional stability.



GRF2070 Application Schematic



GRF2070 EVB Assembly Drawing



Preliminary

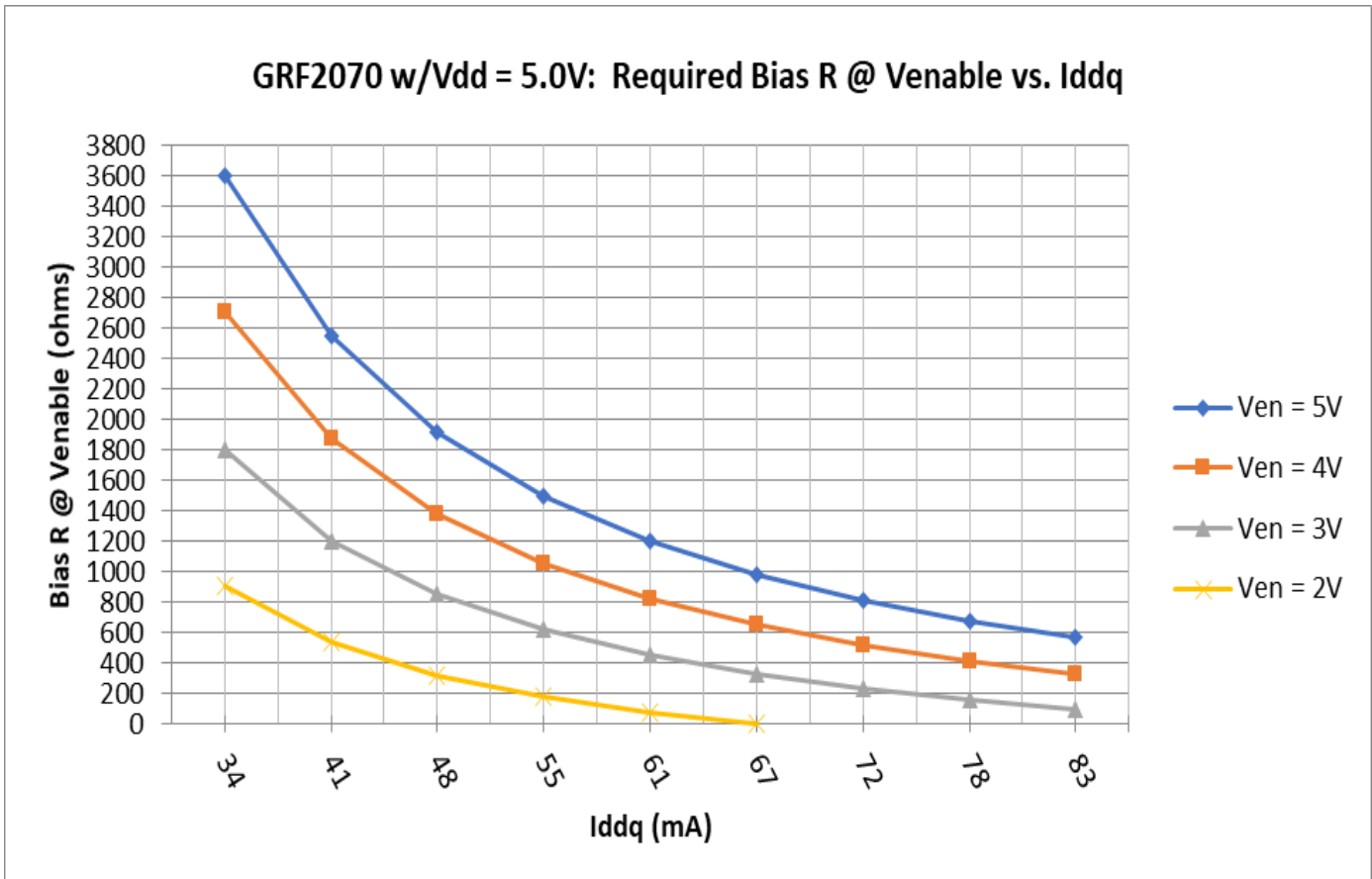
GRF2070

Ultra-Low Noise Amplifier
Tuning Range: 0.4 – 1.5 GHz

GRF2070 Standard Evaluation Board BOM: (0.7 to 0.96 GHz Tune)

Component	Type	Manufacturer	Family	Value	Package Size	Substitution
M1	Resistor (jumper)	Various	—	0 Ohm	0402	ok
M3	Resistor	Various	5%	Sets Iddq	0402	ok
M4	Capacitor	Murata	GJM	47 pF	0402	ok
M8	Inductor	Murata	LQW	22 nH	0402	ok
M10	Capacitor	Murata	GRM	0.1 uF	0402	ok
M11	Capacitor	Murata	GRM	4.7 pF	0402	ok
Evaluation Board	DFN8_2x2_RevA	—	—	—	—	—

GRF2070 Bias Resistor Selection Curves:





Preliminary

GRF2070

Ultra-Low Noise Amplifier
Tuning Range: 0.4 – 1.5 GHz

Data Sheet Release Status:	Notes
Advance	S-parameter and NF data based on EM simulations for the fully packaged device using foundry supplied transistor s-parameters. Linearity estimates based on device size, bias condition and experience with related devices.
Preliminary	All data based on evaluation board measurements in the Guerrilla RF Applications Lab.
Released	All data based on device qualification data. Typically, this data is nearly identical to the data found in the preliminary version. Max and min values for key RF parameters are included.

Information in this datasheet is specific to the Guerrilla RF, Inc. ("Guerrilla RF") product identified.

This datasheet, including the information contained in it, is provided by Guerrilla RF as a service to its customers and may be used for informational purposes only by the customer. Guerrilla RF assumes no responsibility for errors or omissions on this datasheet or the information contained herein. Information provided is believed to be accurate and reliable, however, no responsibility is assumed by Guerrilla RF for its use, nor for any infringement of patents, or other rights of third parties, resulting from its use. Guerrilla RF assumes no liability for any datasheet, datasheet information, materials, products, product information, or other information provided hereunder, including the sale, distribution, reproduction or use of Guerrilla RF products, information or materials.

No license, whether express, implied, by estoppel, by implication or otherwise is granted by this datasheet for any intellectual property of Guerrilla RF, or any third party, including without limitation, patents, patent rights, copyrights, trademarks and trade secrets. All rights are reserved by Guerrilla RF.

All information herein, products, product information, datasheets, and datasheet information are subject to change and availability without notice. Guerrilla RF reserves the right to change component circuitry, recommended application circuitry and specifications at any time without prior notice. Guerrilla RF may further change its datasheet, product information, documentation, products, services, specifications or product descriptions at any time, without notice. Guerrilla RF makes no commitment to update any materials or information and shall have no responsibility whatsoever for conflicts, incompatibilities, or other difficulties arising from any future changes.

GUERRILLA RF INFORMATION, PRODUCTS, PRODUCT INFORMATION, DATASHEETS AND DATASHEET INFORMATION ARE PROVIDED "AS IS" AND WITHOUT WARRANTY OF ANY KIND, WHETHER EXPRESS, IMPLIED, STATUTORY, OR OTHERWISE, INCLUDING FITNESS FOR A PARTICULAR PURPOSE OR USE, MERCHANTABILITY, PERFORMANCE, QUALITY OR NON-INFRINGEMENT OF ANY INTELLECTUAL PROPERTY RIGHT; ALL SUCH WARRANTIES ARE HEREBY EXPRESSLY DISCLAIMED. GUERRILLA RF DOES NOT WARRANT THE ACCURACY OR COMPLETENESS OF THE INFORMATION, TEXT, GRAPHICS OR OTHER ITEMS CONTAINED WITHIN THESE MATERIALS. GUERRILLA RF SHALL NOT BE LIABLE FOR ANY DAMAGES, INCLUDING BUT NOT LIMITED TO ANY SPECIAL, INDIRECT, INCIDENTAL, STATUTORY, OR CONSEQUENTIAL DAMAGES, INCLUDING WITHOUT LIMITATION, LOST REVENUES OR LOST PROFITS THAT MAY RESULT FROM THE USE OF THE MATERIALS OR INFORMATION, WHETHER OR NOT THE RECIPIENT OF MATERIALS HAS BEEN ADVISED OF THE POSSIBILITY OF SUCH DAMAGE.

Customers are solely responsible for their use of Guerrilla RF products in the Customer's products and applications or in ways which deviate from Guerrilla RF's published specifications, either intentionally or as a result of design defects, errors, or operation of products outside of published parameters or design specifications. Customers should include design and operating safeguards to minimize these and other risks. Guerrilla RF assumes no liability or responsibility for applications assistance, customer product design, or damage to any equipment resulting from the use of Guerrilla RF products outside of stated published specifications or parameters.

Guerrilla RF Proprietary Information. Guerrilla RF™ and the composite logo of Guerrilla RF™ are trademarks of Guerrilla RF, Inc. ©2014 Guerrilla RF, Inc. All rights reserved.



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.